

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,259,081 B2
APPLICATION NO. : 10/525288
DATED : August 21, 2007
INVENTOR(S) : James S. Im

Page 1 of 2

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

At column 3, line 14: "sample are provided, in particular, a beam generator can be" should read -- sample are provided. In particular, a beam generator can be --

At column 5, line 22: "FIGS. 4E-4F are irradiations, by the radiation beam pulse" should read -- FIGS. 4E-4F are irradiations, by the radiation beam pulse --

At column 5, line 67: "processing procedure of the present invention under at last" should read -- processing procedure of the present invention under at least --

At column 6, line 30: "incorporated herein by reference. Substantially solar sys-" should read -- incorporated herein by reference. Substantially similar sys- --

At column 7, line 14: "beam intensity in the range of 10 mJ/cm² to 1 J/cm², a pulse" should read -- beam intensity in the range of 10 mJ/cm² to 1J/cm², a pulse --

At column 7, line 15: "duration (FWHM in the range of 10 to 103 nsec, and a pulse" should read -- duration (FWHM) in the range of 10 to 103 nsec, and a pulse --

At column 8, line 61: "150 is capable of patterning the beam pulse 164 so as to" should read -- 150 is capable of patterning the beam pulse 164 so as to --

At column 9, line 60: "the first small- ed region 315 and form a border there" should read -- the first small-grained region 315 and form a border there --

At column 9, line 67: "are smaller than he grains of the region 318. However, the" should read -- are smaller than the grains of the region 318. However, the --

At column 10, line 28: "to laterally grow grams therefrom. The resultant crystallized" should read -- to laterally grow grains therefrom. The resultant crystallized --

At column 10, line 54: "170 because it is no longer irradiating the sample 170." should read -- 170 because it is no longer irradiating the sample 170. --

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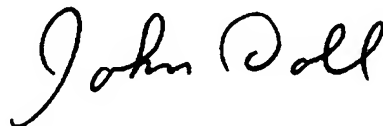
At column 12, line 27: "tion of the sample 170 with sect to the impingement thereof" should read -- tion of the sample 170 with respect to the impingement thereof --

At column 14, line 22: "semiconductor thin film are irradiated and filly melted" should read -- semiconductor thin film are irradiated and fully melted --

At column 15, line 31: "least partial lateral solidification and crystalization of the" should read -- least partial lateral solidification and crystallization of the --

Signed and Sealed this

Seventeenth Day of March, 2009



JOHN DOLL

Acting Director of the United States Patent and Trademark Office